

Standards Enabling Enterprise Class SSDs

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MEMS001



Agenda

Enterprise NVMHCI

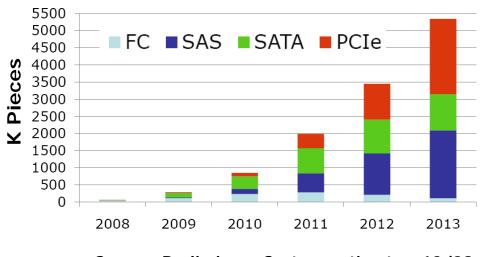
- ONFi 3.0
- Summary



PCI Express* Technology SSD Trend

- PCI Express (PCIe) Technology SSDs are happening
 - Plentiful PCIe lanes
 - Enables > 600 MB/s in one device
 - Lower latency (µsec matter)
 - Opportunity to minimize infrastructure cost with direct attach

Enterprise SSD Outlook by Interface



Source: Preliminary Gartner estimates, 12/09

Fusion-io unveils 80GB ioXtreme PCI Express SSD

By Matthew DeCarlo, TechSpot.com Published: June 8, 2009, 9:15 AM EST

PhotoFast G-Monster PCI Express SSD [1TB PCIe

Boasts750MB/s Transfer Speeds]

Posted March 26th 2009 by Andrew in Computers + Hard Disks & Solid State Drive

PhotoFast

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PCI Express 2.0 Tra

Module Training

Fusion-io is launching a new "Fatal1ty" branded product as they deliver an enthusiastoriented PCI Express solid state drive. The ioXtreme SSD will make use of the PCI-E x4 interface and bear a non-volatile 80GB capacity based on MLC NAND technology





ally, OCZ outed this here PCI-Express SSD way back at CeBIT in March, but it's just in making things super official. Now available with a fresh face and hard specifications, the Z-Drive is g to take on wares by firms like Fusion io and provide blistering transfer rates to a

Micron demos ultra fast 1GB/sec SSD

Pair of solid state disks mounted on PCI-E cards show stunning potential of storage technology



It may be a while before this echnology reaches the average PC or laptop, but Micron has demonstrated potential read speeds of over 1GB/sec on its test Washington SSDs, which are mounted on PCI-E cards.

On Micron's Advanced Storage Blog. Joe Jeddeloh from the company demonstrated the potential of its advanced SLC (single level cell) SSD technology in a particularly amateur and shaky video (see below), but if the claims are correct then Micron is really onto a winner here. The video shows two SSD PCI-E cards running on an eight-core Xeon system. Unfortunately, you can't see he details in the bench arks, but Jeddeloh

Adoption Challenge

- The PCI Express* (PCIe) Technology SSDs that are emerging do not have a standard host controller interface (i.e., register i/f)
 - This requires each vendor to provide a driver with the SSD
- Lack of standard drivers is a challenge to PCIe SSD adoption
 - Requires each SSD vendor to provide a driver for each OS
 - Requires OEMs to validate each SSD with its own driver, increasing validation time and cost
 - Makes adoption of PCIe SSDs more difficult
- To resolve this, industry leaders are defining Enterprise NVMHCI
 - Standard host controller interface (register programming interface) for Enterprise class PCIe SSDs
 - Addresses Enterprise server scenarios with a streamlined and efficient interface enabling very high IOPs



Industry Leaders Driving Enterprise NVMHCI





The Value of Enterprise NVMHCI

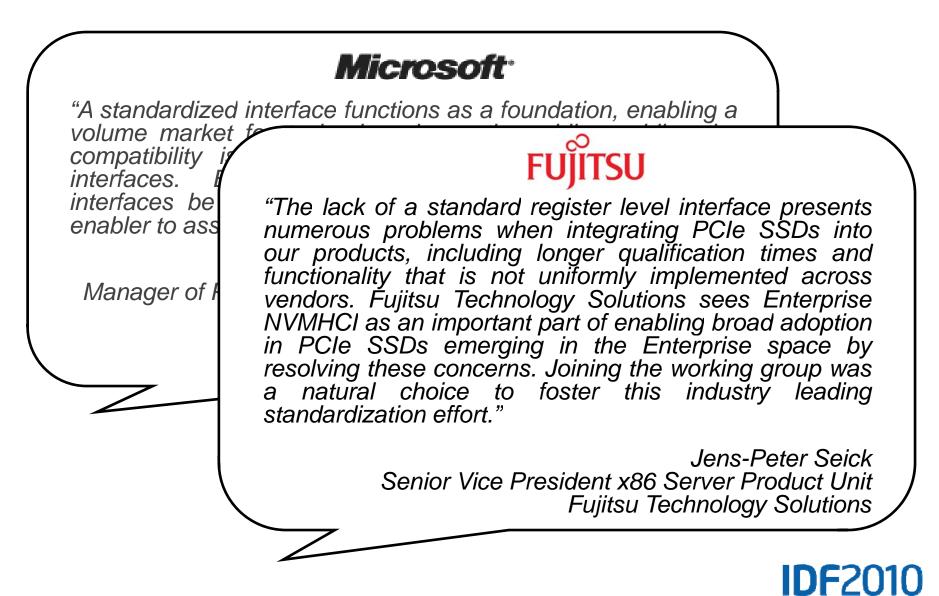
Microsoft^{*}

"A standardized interface functions as a foundation, enabling a volume market for technology innovation while avoiding the compatibility issues that arise from multiple, proprietary interfaces. Enterprise customers are requesting standard interfaces be used on non-volatile-memory products as an enabler to assist broad adoption."

John Loveall Manager of Program Management, Storage and File Systems Microsoft



The Value of Enterprise NVMHCI



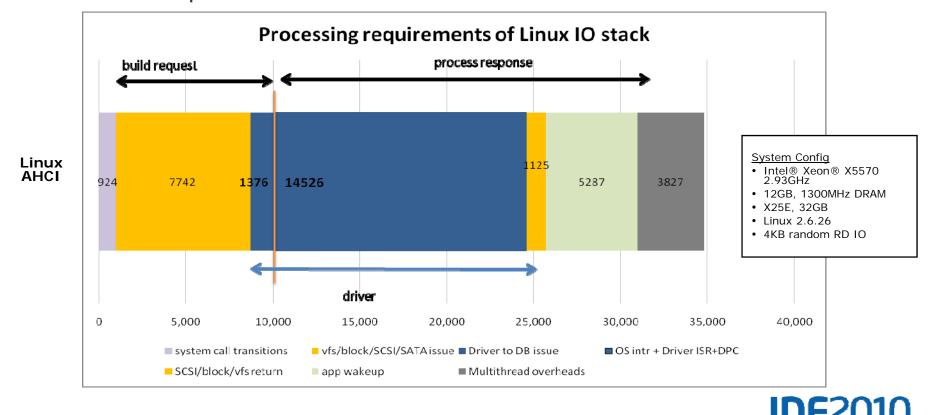
Enterprise NVMHCI Goals

- Goals
 - Address Enterprise server scenarios
 - Enable an efficient interface that can achieve very high IOPs
 - Enable OS vendors to deliver a standard & high performance driver for all PCI Express* (PCIe) Technology SSDs
 - Enable OEMs to qualify / validate a single driver on each OS
 - Ensure features are implemented in a consistent fashion, and thus reduce time to market for PCIe SSDs
- To realize goals quickly
 - Utilize existing & efficient NVMHCI Workgroup team
 - Leverage from NVMHCI 1.0 where it makes sense
 - Take advantage of extending drivers already written or underway for NVMHCI 1.0



Optimization Points, example

- The Linux* stack using AHCI is ~ 35,000 clocks / IO
- A large impact is uncacheable reads, ~ 2000 clocks each
 - Minimum of 4 uncacheable reads required with AHCI
- Enterprise NVMHCI is eliminating uncacheable reads for command issue/completion



Source: Intel internal analysis

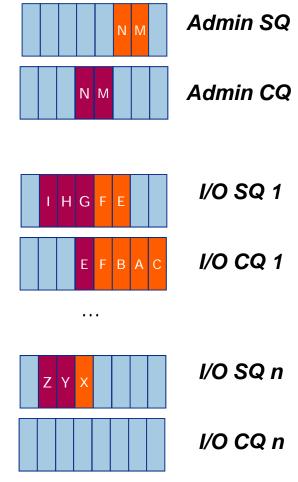
Interface Attributes

- Eliminate performance bottlenecks seen in other interfaces
 - Eliminate uncacheable reads from command issue/completion
 - Ensure maximum of 1 MMIO write in command issue path
 - Support deep command queues
 - Avoid "pointer chasing", aggregate command information
- Support efficient and streamlined command set
 - ~10 to 15 optimized NVM commands
 - Do not carry forward HDD command set legacy
- Support for MSI-X and interrupt aggregation
- Support for IO virtualization (e.g. SR-IOV)
- Efficient error handling & *driver* translation into SCSI management architectures prevalent in Enterprise



Paired Queue Mechanism

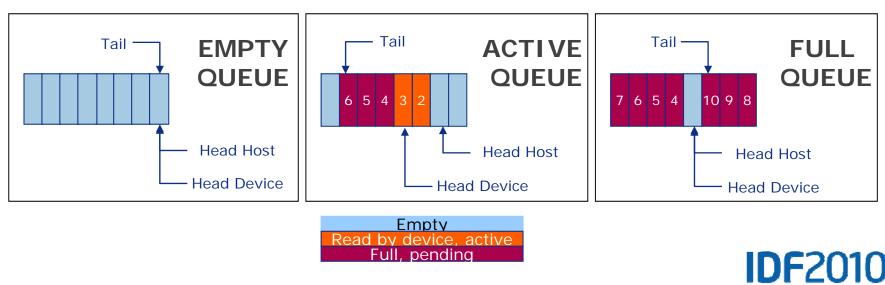
- Command submission & completion use a paired queue mechanism (submission and completion queues)
- The Admin queue carries out functions that impact the entire device
 - E.g. Queue creation and deletion, command abort
- Driver creates the number of queues that match system config & workload
 - E.g. On a 4 core system, devote a queue pair per core to avoid locking and ensure structures in right core's cache





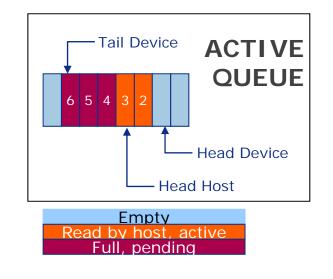
Submission Queue Details

- A submission queue (SQ) is a circular buffer with a fixed slot size that the host uses to submits commands for execution
- The host updates an SQ Tail doorbell register when there are 1 to n new commands to execute
 - The old SQ Tail value is simply overwritten in the device
- The device reads SQ entries in order and removes them from the SQ, then may execute those commands out of order



Completion Queue Details

- A completion queue (CQ) is a circular buffer with a fixed slot size that the device posts status to for completed commands
- The device identifies the command that completed by the SQ Identifier and the Command Identifier (assigned by software)
 - Multiple SQs can use the same completion queue
- The latest SQ Head pointer is returned in the status to avoid a register read for this information
- The Phase (P) bit indicates whether an entry is new, and inverts each pass through the circular buffer



Completion Queue Entry						
SQ Identifier	SQ Head Pointer					
Status Field	Command Identifier					
+ 2 reserved Dwords	IDF 2010					

Register Set

- The device indicates capabilities and version
- Interrupts are indicated via
 register for device failures only
 - Normal command driven interrupts processed via CQ
- Admin Queue configuration is via registers
 - All other queues are created via Admin Queue commands
- Scalable to large number of SQ/CQ based on requirements
- Single "port" per virtual device, with multiple LBA namespace access

Symbol	Description
CAP	Controller Capabilities
VS	Version
IS	Interrupt Status
CMD	Command and Status
Reserved	Reserved
AQA	Admin Queue Attributes
ASQ	Admin Submission Queue Base Address
ACQ	Admin Completion Queue Base Address
SQ0TDBL	Submission Queue 0 Tail Doorbell (Admin)
CQ0HDBL	Completion Queue 0 Head Doorbell (Admin)
SQ1TDBL	Submission Queue 1 Tail Doorbell
CQ1HDBL	Completion Queue 1 Head Doorbell
SQ2TDBL	Submission Queue 2 Tail Doorbell
CQ2HDBL	Completion Queue 2 Head Doorbell
SQyTDBL	Submission Queue y Tail Doorbell
CQyHDBL	Completion Queue y Head Doorbell



Data Transfer Optimization

- Out of order data transfer is important for SSDs
- Walking a scatter/gather list (SGL) to determine where data starts for a transfer is inefficient
- A fixed size SGL entry enables efficient out of order data & simplifies hardware
- Better approach: Page lists
 - First entry contains an offset
 - "Middle" entries are full page in size
 - Last entry may be less than a page
- The command includes three entries to optimize for 4KB & 8KB I/O
 - For a larger transfer, third entry points to a list of entries

First Entry

Page Base Address	Offset				
Page Base Address Upper					

Second Entry

Page Base Address	00h
Page Base Address	Upper

Pointer to Additional Entries

PRP List Address	00h
Page List Address	Upper



Timeline & Opportunity

- Schedule
 - Apr 2010: 0.5 revision
 - Jul 2010: 0.7 revision
 - Sep 2010: 0.9 revision (erratum only after this point)
 - Oct 2010: Release candidate (30-day review)
 - Nov 2010: 1.0 release
- To get involved in the specification definition, join the NVMHCI Workgroup
 - Details at http://www.intel.com/standards/nvmhci

Schedule enables product intercept in 2012.



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ONFi Workgroup History & Results

- NAND was the only commodity memory with no standard i/f
- The Open NAND Flash Interface (ONFi) Workgroup was formed in May 2006 to drive standardization for the raw NAND Flash interface

	Q3 Q4 Q1 '06 '06 '07		Q2 Q3 Q4 Q1 '08 '08 '08 '09	Q2 Q3 Q4 Q1 '09 '09 '09 '10	
Specification	ONFI 1.0	ONFI 2.0	ONFI 2.1 C	ONFI 2.2	
Features	Standard electrical & protocol interface, including base command set	Defined a high speed DDR interface, tripling the traditional NAND bus speed in common use	Included additional features and support for bus speeds up to 200 MB/s	Added features including LUN reset, enhanced program page register clear, and ICC measurement specs	
Maximum Speed	50 MB/s	133 MB/s	200 MB/s	200 MB/s	
Other Activities		ostracted D 1.0	ONFI – JEDE	C Collaboration	



OPEN NAND



A-Data Aleph One **ASMedia Technology Biwin Technology** Data I/O **ENE Technology** FCI **Fusion Media Tech** Hitachi GST Inphi **Kingston Technology** Macronix Metaram Nvidia Power Quotient Int. SandForce Silicon Integrated Sys. Skymedi Synopsys Teradyne UCA Technology Western Digital

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Micron

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ONFI enjoys support of 90+ members.



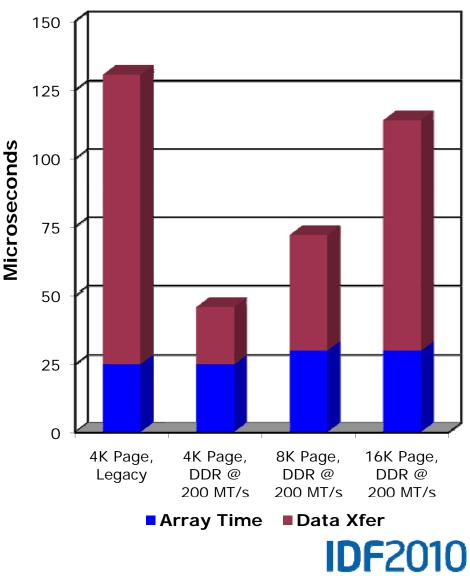
ONFi Workgroup Development

- The ONFi Workgroup has two active development efforts
- ONFi 3.0
 - Scales the NAND interface from 200 MT/s to 400 MT/s
 - Backwards compatible with ONFi 1.x and 2.x
- EZ NAND (Error Correction Code Zero NAND)
 - Enables NAND lithography dependent functions to be separated from the host
 - ECC (and other functions) can be offloaded into an ASIC stacked in the NAND package, while still using normal NAND protocol (Program, Erase, etc)
 - Alleviates the burden from the host of keeping pace with rapidly changing NAND if desired



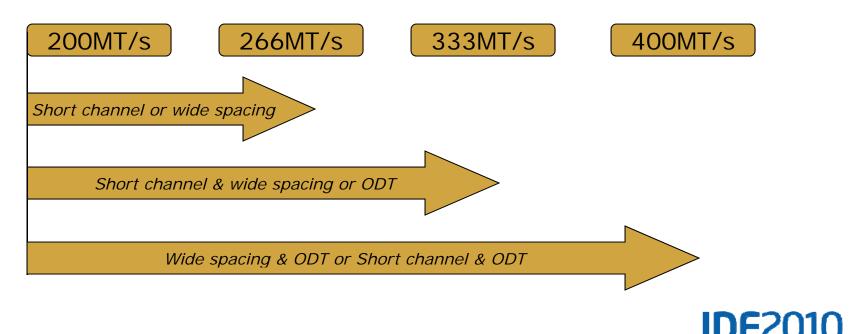
Continuing Scaling Requirement

- As NAND lithographies shrink, page sizes increase
- The page size increases for performance scaling
 - Array times slow down a bit, so send more data in each page to compensate
- The NAND bus needs to keep pace with page scaling, or the bus will be the limiting factor
 - E.g. 16KB page data transfer time is **2.5X** the array time



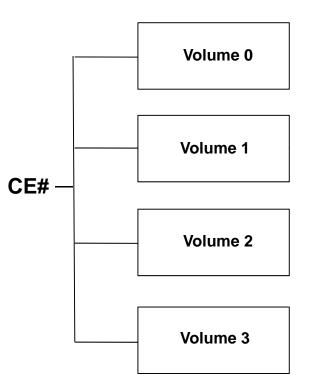
The Path to 400 MT/s

- Key enablers for ONFi 3.0 include:
 - A shorter channel (controller distance to the NAND)
 - Wider spacing between signals
 - On-die termination
 - Complementary clock and DQS signals
- Reaching speed grades requires a combination of enablers



CE# Pin Reduction

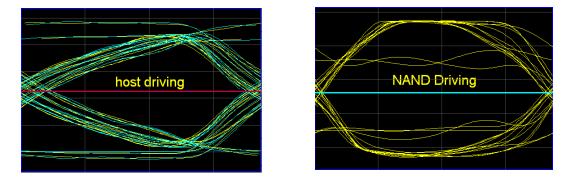
- For a reasonable capacity SSD, there are often 32 or more CE# pins
 Each NAND package has 2 to 4 CE#s
- CE# is a slow signal, and all of these pins add cost to the SSD controller
- ONFI 3.0 includes a mechanism to share CE#s across die & packages
- Each target is assigned a "volume" at power-on
- Each volume is addressed by the host and stays active until the next volume is addressed



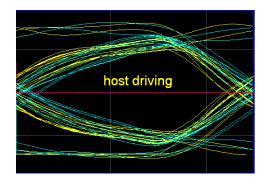


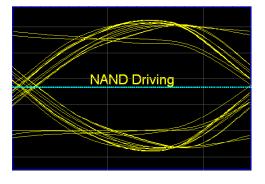
Benefit of On-Die Termination

- Data eye at 266 MT/s without ODT
 - Passable, but getting close to the edge



Data eye at 400 MT/s with On-Die Termination
 – ODT is the key enabler for 400 MT/s operation







On-die Termination Control

- Each LUN (die) may be the terminator for any volume
 - Terminator for its volume: Target termination
 - Terminator for another volume: Non-target termination
- At initialization, the LUN is configured with the volumes it will terminate for
 - Note: Many LUNs will not terminate for any volume
- If a command is issued to a volume the LUN is the terminator for, it snoops and terminates when data is transferred

Matrix of volumes that LUN may terminate for

Volume	7	6	5	4	3	2	1	0
Volume Byte 0	VOL							
	7	6	5	4	3	2	1	0
Volume Byte 1	VOL							
	15	14	13	12	11	10	9	8

ONFi 3.0 targeted for spec completion in Q3.



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Summary

- Enterprise NVMHCI enables broader adoption of PCI Express* (PCIe) Technology SSDs
 - Enables standard OS driver support, simplifies OEM qualification, and decreases time to market
 - Specification will be completed in November to enable
 PCIe SSD product intercept in 2012
- ONFI 3.0 delivers 400 MB/s per NAND channel, enabling next generation SSDs
 - Specification will be completed in 2H of the year

Enterprise NVMHCI and ONFI 3.0 standards enable next generation high performance SSDs.



Call to Action

- Get involved in the Enterprise NVMHCI specification development
 - Information on joining the Workgroup at http://www.intel.com/standards/nvmhci
- Get involved in the ONFi 3.0 specification development
 - Information on joining the ONFi Workgroup at http://onfi.org/membership/join
- Use these standards to deliver your next generation SSD solution



Additional sources of information on this topic:

- Other Sessions
 - MEMS002: Designing Solid-State Drives (SSDs) into Data Center Solutions
 - MEMS003: Understanding the Performance of Solid-State Drives (SSDs) in the Enterprise
 - MEMS004: Enterprise Data Integrity and Increasing the Endurance of Your Solid-State Drive (SSD)
- Learn more about Enterprise NVMHCI at: http://www.intel.com/standards/nvmhci
- Learn more about ONFI 3.0 at: http://www.onfi.org



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